Excitonic versus electron-hole liquid phases in Tm [Se,Te] com pounds

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We discuss, from a theoretical point of view, excitonic phases at the pressure induced sem iconductor-sem in etal transition in Tm Se_{0:45}Te_{0:55}, focusing, in particular, on the stability against an electron-hole liquid. The electron-hole pair density parameter r_s (E $_g$;T) is calculated within the quasi-static plasm on pole approximation as a function of temperature T and energy gap E $_g$ and converted into E $_g$ (r_s ;T). A comparison of this quantity, which is the electron-hole pair chemical potential, with the exciton binding energy reveals that excitons should be suppressed in contrast to experimental evidence for excitonic phases. We suspect therefore inter-valley exciton scattering and exciton-phonon scattering to substantially stabilise excitons in Tm Se_{0:45}Te_{0:55}.

KEYW ORDS: sem iconductor-sem in etal transition, electron-hole liquids, exciton condensation

1. Introduction

The possibility of an excitonic insulator { understood as a m acroscopic, phase coherent quantum state (exciton condensate) { separating below a critical tem perature a sem iconductor (SC) from a sem in etal (SM), has been anticipated by theorists long time ago.¹ Experim entalefforts, how ever, to establish this phase in real com pounds largely failed. The m ost prom ising candidates so far are the hexaborides,² where the unexpected ferrom agnetism m ay be interpreted in terms of a doped excitonic insulator,^{3,4} and Tm Se_{0:45}Te_{0:55}, where the unusual therm al di usivity m ay be due to a super uid exciton state.⁵

W e focus on Tm Se_{0:45} Te_{0:55}. In a series of experiments, W achter and coworkers com piled strong evidence for excitonic phases in the vicinity of the pressure-induced SC – SM transition in Tm Se_{0:45} Te_{0:55}.⁵⁽⁷⁾ In particular, the anom alous increase of the electrical resistivity in a narrow pressure range around 8 kbar indicated the appearance of a new phase below 250 K .W achter and cow orkers suggested that this new phase m ight be an \excitonic insulator", and, assuming the energy gap E_g to decrease with increasing pressure, constructed a phase diagram for Tm Se_{0:45}Te_{0:55} in the E_g T plane.⁶ Later they found in the same m aterial a linear increase of the therm ald i usivity below 20 K and related this to a super uid exciton state.⁵ B oth excitonic phases are located on the SC side of the SC -SM transition in Tm Se_{0:45}Te_{0:55}.

In our previous work⁸ we presented a theoretical analysis of these astonishing experimental notings. We calculated for a model minicking the situation in $Tm Se_{0:45}Te_{0:55}$ the phase boundary $T_c (E_g)$ for an excitonic insulator and investigated the composition of its environment. Our main conclusions were: (i) The phase boundary constructed from the resistivity data does not embrace the excitonic insulator. Instead, it most probably traces the exciton-rich region above an excitonic insulator, where excitons dom inate the total density, provide abundant scattering centres for the charge carriers, and induce the observed resistivity anomaly. (ii) The linear increase of the therm al di usivity below 20 K, on the other hand, could signal exciton condensation. The large electron-hole m ass asym metry places the excitonic insulator entirely on the SC side, where it is supported by strongly bound, bosonic excitons. A transition to a super uid state, sim ilar to the transition in liquid He 4, is thus conceivable and could give rise to the observed atypical therm aldi usion.

We based our calculation on an elective-mass, W annier-type model for electrons in the lowest conduction band (CB) and holes in the highest valence band (VB), with an indirect energy gap separating the two bands, a multiplicity factor to account for three equivalent CB m inim a arising from the fcc crystal structure of Tm Se_{0:45}Te_{0:55}, and a statically screened C oulom b potential operating between the constituents of the model (in contrast to the quasi-static screening model used below). Because of the limitations of the model, which, for instance, neglects lattice elects, we could not obtain complete quantitative agreem ent between theory and experiment. Yet, our results indicate that W achter and cow orkers⁵⁽⁷⁾ m ay have seen an exciton condensate.

C learly, within an e ective electron-hole model quantitative agreem ent between experiment and theory cannot be expected. Instead of augmenting the model with additional degrees of freedom, we still want to stay in the present paper within its bounds and discuss the possibility of an electron-hole liquid⁹ which competes with excitonic phases in materials where the band structure is multi-valleyed. The results will further benchmark the model and thus guide its modi cation.

2. M ethod

The therm odynamics of an electron-hole liquid is contained in the electron-hole pair chemical potential $_{eh}$ ($r_s;T$) which depends on the electron-hole pair density parameter r_s and the temperature T.⁹ In our case, $_{eh} = E_g$, with E_g the energy gap xed by the external pressure. Therefore, we rst have to determ ine r_s ($E_g;T$) and then convert this relation into E_g ($r_s;T$).

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Fig. 1. The band structure of the e ective-m ass, W annier-type m odel. W e m easure m om enta k for the CB electrons and VB holes from the respective extrem a of the bands which, in reality, are separated by w = K =2 where K is the reciprocal lattice vector connecting the with the X points of the B rillouin zone for a fcc lattice. The energy gap E_g varies continuously through zero under pressure. Solid (dashed) parabola denote the bare (renormalised) energy bands. Note, the auxiliary chem ical potentials i are de ned with respect to the shifted band edges. The factors g_i account for spin and the number of equivalent valleys.

C om paring E_g (r_s ; T) with the exciton binding energy and analysing for xed temperature its r_s -dependence enables us to determ ine the region in the E_g T plane where an electron-hole liquid m ay be favoured over excitonic phases. We calculate E_g (r_s ; T) in the quasi-static plasm on-pole approximation.¹⁰

The schem atic band structure used in Ref.⁸ to m odel $Tm Se_{0:45}Te_{0:55}$ is shown in Fig. 1. W ithin the quasistatic plasm on-pole approximation the CB electron (i = 1) and VB hole (i = 2) selfenergies, leading, at nite lling, to the renorm alization of the energy bands (dashed parabola in Fig. 1), can be written as

$$i(k) = \sum_{i}^{sx} (k) + \sum_{i}^{ch} (k);$$
 (1)

where the rst term,

$$\sum_{i}^{sx} (k) = \sum_{k^{0}}^{X} V_{s} (k \quad k^{0}) n_{F} (i (k^{0}) \quad i); \quad (2)$$

denotes the exchange energy and the second,

$${}_{i}^{ch}(k) = \frac{1}{2} \frac{X}{k^{0}} V_{s}(k^{0}) V_{0}(k^{0}) ; \qquad (3)$$

the C oulom b-hole energy. Here, $V_0\left(q\right)=4~e^2="_0q^2$ is the C oulom b potential reduced by the background dielectric constant $"_0, V_s\left(q\right)$ is the statically screened C oulom b potential to be de ned below, $_i\left(k\right)=k^2=2m_i~(m_i \mbox{ are the e ectivem asses}), \mbox{ and } n_F($) is the Ferm i function. In contrast to the static approximation used in Ref., 8 which replaces directly in the H am iltonian $V_0\left(q\right)$ by $V_s\left(q\right)$, the selfenergies contain now not only the exchange corrections but also the C oulom b-hole.

The screened Coulomb potential in Eqs. (2) and (3) is the static lim it of the dynam ically screened Coulomb

potential,

$$V_{s}(q) = V_{s}(q;0) = V_{0}(q) = "(q;0);$$
 (4)

where the dielectric function is given by

$$\frac{1}{"(q;!)} = 1 + \frac{!_{p_1}^2}{(!+i)^2 ! (q)^2};$$
(5)

with an e ective plasm on dispersion,

$$! (q)^{2} = !_{p1}^{2} 1 + \frac{q}{q_{s}}^{2} + C \frac{q^{2}}{4m_{1}} + \frac{q^{2}}{4m_{2}}^{2}; \quad (6)$$

constructed in such a way that sum rules are satis ed.¹⁰ W hen the plasmon-pole approximation is constructed from the Lindhard dielectric function, the coe cient C = 1. It can be however also used as a t parameter to correct for the overestimation of screening within the quasi-static approximation. In that case 1 C 4.¹⁰ The screening wave number,

$$q_{s} = \frac{3}{\frac{4}{n_{0}}} \frac{\frac{2}{n_{0}}}{\frac{2}{n_{0}}} \frac{\frac{2}{n_{1}}}{n_{1}} + \frac{\frac{2}{n_{0}}}{\frac{2}{n_{0}}} \frac{n_{2}}{n_{2}}; \quad (7)$$

and plasm a frequency,

$$!_{p1} = \frac{5 \frac{4 e^2}{m_0} \frac{n_1}{m_1} + \frac{n_2}{m_2}}{(m_0 + m_1)^2}; \quad (8)$$

entering Eq. (6) depend on the CB electron and VB hole densities given, respectively, by

$$n_1 = g_1 \qquad n_F (1 (k) \ 1);$$
 (9a)

$$n_2 = g_2 \qquad n_F (_2 (k) \qquad _2);$$
 (9b)

where the multiplicity factors g_i contain the spin and the number of equivalent valleys.

The main e ect of the selfenergies $_{i}$ is a rigid, kindependent shift of the single particle dispersions leading to a renorm alised band gap E_g. This situation has been anticipated in Eqs. (2), (9a), and (9b), where we introduced auxiliary chem icalpotentials $_{i}$, m easured from the shifted band edges (see Fig. 1). By construction,

$$_{1} + _{2} = E_{q}$$
: (10)

The bare energy gap E_g , that is, the parameter which is experimentally controlled via pressure, is given by

$$E_g = E_g _1(0) _2(0)$$
: (11)

Supplem enting Eqs. (10) and (11) with the condition of charge neutrality,

$$n_1 = n_2$$
; (12)

we obtain a closed set of equations for the three unknown parameters $_1$ and $_2$, and E_{g} .

To construct from Eqs. (10) { (12) the electron-hole pair chem ical potential $E_g(r_s;T)$, we proceed as follows: First, we calculate from Eqs. (12), (10), (9b) and (9a), the auxiliary chem ical potentials $_i$ as a function of E_g and T. Inserting $_i(E_g;T)$ in Eqs. (7) and (8), we obtain $q_s(E_g;T)$ and $!_{p1}(E_g;T)$, which enables us to determ ine V_s and thus the selfenergies $_i$ in the whole E_g T plane. V is Eq. (11) we then obtain the important relation



Fig. 2. Shifted energy gap E_g as a function of the pressure-tuned energy gap E_g and temperature T for Tm Se_{0:45}Te_{0:55} parameters: = 0:015, g₁ = 6, and g₂ = 2. The dotted line denotes the energy where the excitonic instability would occur at T = 0 and the dashed line gives E_g (E_g ;T = 0:152) in the static approxim ation.

 $E_g (E_g;T)$. Finally, we use either Eq. (9a) or Eq. (9b) to m ap, for a given temperature T, the renormalised energy gap E_g on to the electron-hole pair density n $n_1 = n_2$. U sing the density parameter $r_s = (3=4 \text{ n} \frac{3}{\text{A}})^{1=3}$, with a_X the exciton B ohr radius de ned in the next section, instead of the pair density, we nd $E_g (r_s;T)$.

3. Results

In the following, we measure energies and lengths in units of the exciton Rydberg $R_X = 1=2m a_X^2$ and the exciton Bohr radius $a_X = "_0=m e^2$, respectively (~ = 1). The model shown in Fig. 1 is then completely specied by the multiplicity factors g_i and the elective mass ratio = $m_1=m_2$. For Tm Se_{0:45}Te_{0:55} the corresponding values are $g_1 = 6$, $g_2 = 2$, and $0.015.^{5,8}$ Due to the lack of data about band gap renorm alization in Tm Se_{0:45}Te_{0:55}, we cannot use C in Eq. (6) as a t parameter. Thus, C = 1, which alm ost certainly overestimates screening.

The shifted energy gap E_g as a function of the energy gap E_g is shown in F ig. 2 for several temperatures. First we note the drastic di erence to the static approximation (V₀ ! V_s in the H am iltonian). Whereas in the static approximation E_g decreases monotonously with E_g for all temperatures, the quasi-static approximation gives, for some E_g-range, a triple-valued E_g for T < 0.305. Because of the one-to-one correspondence between E_g and the pair density n, this means the system cannot choose a unique pair density. As a consequence, there may be parts in the E_g T-plane where an electron-hole gas coexists with an electron-hole liquid. Note, the renormalised band gap E_g resembles the selfenergy parameter S introduced before to set up a H artree-Fock description of the gas/liquid transition in a generic electron-hole plasma.¹²

The corresponding pair chem ical potential $E_g(r_s;T)$ is shown in Fig. 3. Various subtle points should be noticed before we can attempt an interpretation of the data. First, $E_g(r_s;T)$ does not asymptotically merge with the exciton Rydberg for r_s ! 1. Thus, the results in the ex-



Fig. 3. Electron-hole pair chem ical potential $E_g(r_s;T)$ as a function of electron-hole pair density parameter r_s and tem perature T for Tm Se_{0:45}Te_{0:55} parameters: = 0:015, $g_1 = 6$, and $g_2 = 2$. The dotted line indicates where the excitonic instability would occur at T = 0 and the dashed line gives $E_g(r_s;T = 0:152)$ in the static approximation. Note, for T < 0:305, the isotherm s go through a m inimum.

trem e dilute lim it are awed, not only in the quasi-static approximation (solid lines) but also in the static approximation (dashed line). This is a well-known shortcoming of random -phase-approximation based screening models, which neglect multiple-scattering between charged carriers. Including multiple-scattering (ladder diagram s) in the quasi-static (static) approximation would force the chemical potential E_g (r_s ;T) to approach for r_s ! 1 the exciton Rydberg from below (above). Second, the densities of interest are rather low ($r_s \& 1$). Corrections due to multiple scattering are therefore not necessarily small and should be included, a form idable task beyond the scope of the present paper.

W ith these caveats in m ind we now extract the physical implications of the data shown in Fig. 3. As expected from the E_q -isotherm s, the model shown in Fig. 1 yields for Tm Se0:45 Te0:55 parameters a chem ical potential which shows the typical van-der-W aals behaviour: Above a critical tem perature (T_{crit} 0:254), the chem ical potential increases monotonously with density (re- $1=n^{1=3}$). Below the critical tem perature, the call: r_s chem icalpotential has a localm axim um and a localm inimum. This can be most clearly seen from the T = 0.203isotherm . A Maxwell construction would thus give the equilibrium chemical potential and the coexistence region between the gaseous and the liquid phases. Anticipating however the correct dilute lim it, a Maxwell construction cannot be made and the minimum simply indicates a jump in the pair densities, that is, for large enough energy gaps the pair density n drops to zero.¹¹ Only when the exciton binding energy is below them in im um of the chem ical potential, a gas/liquid transition and with it a coexistence region could appear. In that case, excitons would be also stable in a certain range.Because of the experim entalevidence for excitonic phases, we expect this situation to be actually realised in Tm Se_{0:45}Te_{0:55}.

The minimum of the pair chemical potential



Fig. 4. Phase boundaries obtained for $Tm Se_{0:45}Te_{0:55}$ parameters: = 0:015, $g_1 = 6$, and $g_2 = 2$. The thick dotted line is the 50% -contour of the bound state fraction ⁸ B eyond the dashed line excitons disappear because of the M ott e ect and the grey region denotes the excitonic insulator (E I).⁸ At the full diam ond on the horizontal thin dotted line the linear increase of the therm al di usivity has been experimentally found⁵ and at the full circle n_1^b 1:3 10^{21} cm ³⁸ in good agreement with the experimentally estimated exciton density 3:9 10^{21} cm ³. The open circles are the points where E_g (r_s ; T) goes through the minimum. The energy gap of Tm Se_{0:45}Te_{0:55} at am bient pressure is given by the vertical thin dotted line.

 E_g (r_s ; T) is below the exciton Rydberg. Therefore, taking the correct r_s ! 1 limit of E_g (r_s ; T) into account, our results for the pair chemical potential suggest that in the W annier-type m odel excitons and thus excitonic phases (exciton gas, excitonic insulator) are unstable against a m etallic phase. Anticipating, in addition, the decrease of the exciton binding energy with increasing density, the m etallic phase would be in fact favoured over most of the relevant parameter range discussed in Ref.⁸ and in stark contrast to the experimentally observed increase of the resistivity.

This can be seen in Fig. 4 which combines the points where $E_g(r_s;T)$ is minimal with (i) the phase boundary of the excitonic insulator, (ii) the 50% -contour of the bound state fraction $= n_1^b = (n_1^f + n_1^b) (n_1^f \text{ and } n_1^b \text{ are the free and the bound part of the total density obtained from a T-m atrix calculation of the total density), and (iii) the M ott line beyond which excitons disappear because P auliblocking and screening lead to a vanishing exciton binding energy. All of it has been calculated in R ef.⁸ within the static screening m odel. We expect how ever the quasi-static approximation to give similar results.$

O ne of our main conclusions in Ref.⁸ was that the resistivity anomaly, that is, the experimentally observed increase of the resistivity in a narrow pressure range, is most probably due to exciton-electron and exciton-hole scattering which would be very e cient above an excitonic insulator. Indeed, the tem perature range, where the 50% -contour is located, coincides roughly with the tem perature range where the anom aly has been detected. In contrast, the analysis of the pair chem ical potential perform ed in this paper suggests excitons in that region to be unstable against a metallic electron-hole plasma. An increase of the resistivity is how ever hard to reconcile with a metallic phase. We expect therefore excitons in Tm Se_{0:45}Te_{0:55} to be stabilised by band structure effects beyond the model shown in Fig. 1 and additional scattering processes. That the elective-mass, W anniertype model may not be quite adequate can be also seen from the fact that the experimentally determined exciton Rydberg for Tm Se_{0:45}Te_{0:55} is 75 meV whereas the energy gap at ambient pressure is 135 meV and thus only 1:8 B_x (vertical thin dotted line in Fig. 4).

In analogy to the hexaborides,¹¹ we expect coherent inter-valley scattering of excitons to increase the exciton binding energy. Additionally, exciton-phonon scattering should also increase the binding energy of an exciton in Tm Se_{0:45}Te_{0:55} because the narrow VB m akes the exciton very susceptible to phonon dressing. In fact, there is plenty of experim ental evidence for strong excitonphonon coupling in Tm Se_{0:45}Te_{0:55}.⁵ Both scattering processes should be studied in detail, ideally in a model which avoids the e ective mass approximation and keeps the full band structure. If it turns out that in a more realistic model the exciton binding energy is still above the chem icalpotential of the m etallic phase, exciton ic phases must be ruled out in Tm Se0:45 Te0:55.0 n the other hand, if the exciton binding energy is pushed below the minimum of the metallic chemical potential, and that is not unrealistic considering the energy gain coherent intervalley scattering alone can yield if the band structure perm its it_r^{11} excitons are stable, at least in some pressure range, and the excitonic instability leading to an excitonic insulator could take place in Tm Se0:45 Te0:55 before an electron-hole gas-liquid transition interferes.

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